MCH3484

Power MOSFET 20V, 40mΩ, 4.5A, Single N-Channel



- On-Resistance $RDS(on)1=33m\Omega$ (typ)
- 0.9V Drive
- Pb-Free, Halogen Free and RoHS Compliance
- ESD Diode-Protected Gate

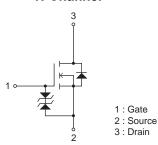
Specifications

Absolute Maximum Ratings at $Ta = 25^{\circ}C$

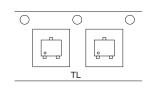
Parameter	Symbol	Value	Unit
Drain to Source Voltage	VDSS	20	V
Gate to Source Voltage	VGSS	±5	V
Drain Current (DC)	ID	4.5	А
Drain Current (Pulse) PW≤10μs, duty cycle≤1%	I _{DP}	18	A
Power Dissipation When mounted on ceramic substrate (900mm ² ×0.8mm)	PD	1.0	W
Junction Temperature	Tj	150	°C
Operating Temperature	Topr	–5 to +150	°C
Storage Temperature	Tstg	–55 to +150	°C



Electrical Connection N-Channel



Packing Type : TL Marking





Thermal Resistance Ratings

Parameter	Symbol	Value	Unit	
Junction to Ambient When mounted on ceramic substrate (900mm ² × 0.8mm)	$R_{ hetaJA}$	125	°C/W	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

ORDERING INFORMATION

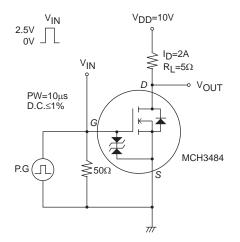
See detailed ordering and shipping information on page 5 of this data sheet.

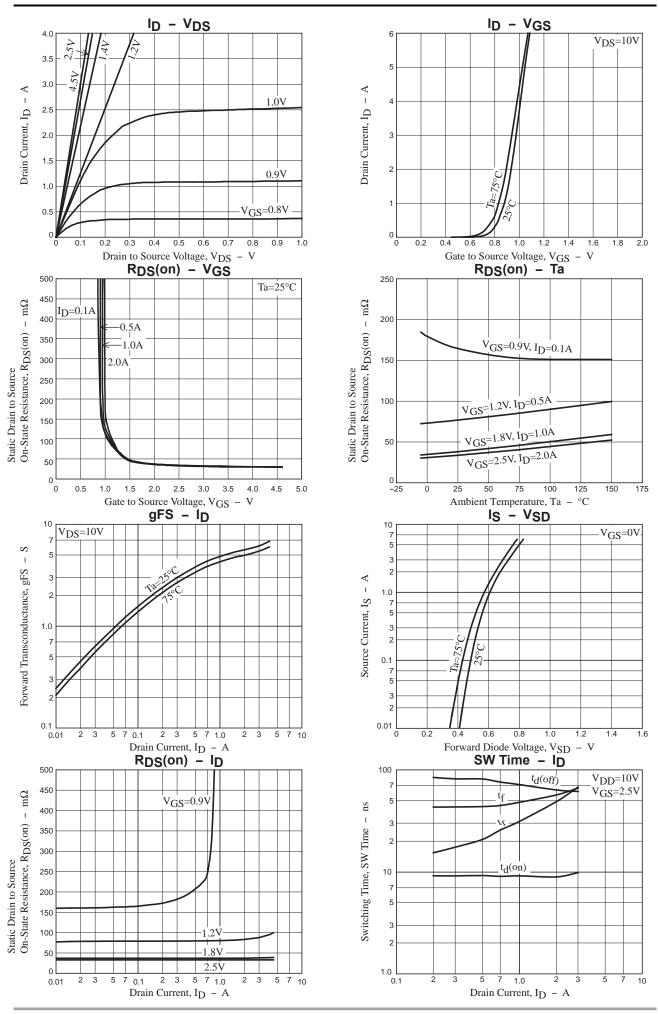
Electrical Characteristics at Ta = 25°C

Deveryor	O wash at		Value			
Parameter Symbol Conditions		min	typ	max	Unit	
Drain to Source Breakdown Voltage	V(BR)DSS	ID=1mA, VGS=0V	20			V
Zero-Gate Voltage Drain Current	IDSS	V _{DS} =20V, V _{GS} =0V			1	μA
Gate to Source Leakage Current	IGSS	V _{GS} =±4V, V _{DS} =0V			±10	μA
Gate Threshold Voltage	VGS(th)	V _{DS} =10V, I _D =1mA	0.3		0.8	V
Forward Transconductance	9FS	V _{DS} =10V, I _D =2A		5.6		S
Static Drain to Source On-State Resistance	R _{DS} (on)1	I _D =2A, V _{GS} =2.5V		33	40	mΩ
	R _{DS} (on)2	ID=1A, VGS=1.8V		37	49	mΩ
	R _{DS} (on)3	I _D =0.5A, V _{GS} =1.2V		79	119	mΩ
	R _{DS} (on)4	I _D =0.1A, V _{GS} =0.9V		165	330	mΩ
Input Capacitance	Ciss			630		pF
Output Capacitance	Coss	V _{DS} =10V, f=1MHz		75		pF
Reverse Transfer Capacitance	Crss			65		pF
Turn-ON Delay Time	t _d (on)	See specified Test Circuit		8.9		ns
Rise Time	tr			49		ns
Turn-OFF Delay Time	t _d (off)			63		ns
Fall Time	tf			57		ns
Total Gate Charge	Qg	V _{DS} =10V, V _{GS} =2.5V, I _D =4.5A		11		nC
Gate to Source Charge	Qgs			0.9		nC
Gate to Drain "Miller" Charge	Qgd	7		1.8		nC
Forward Diode Voltage	V _{SD}	I _S =4.5A, V _{GS} =0V		0.8	1.2	V

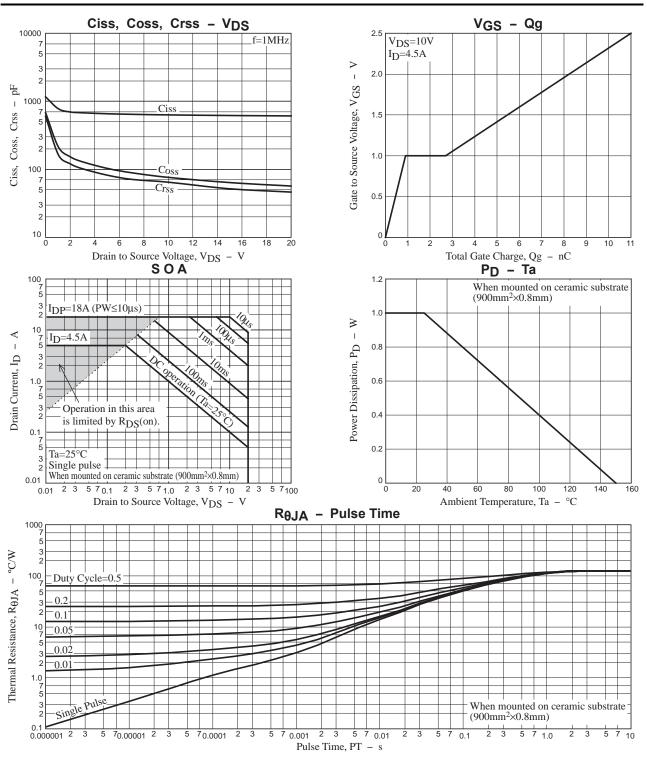
Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

Switching Time Test Circuit





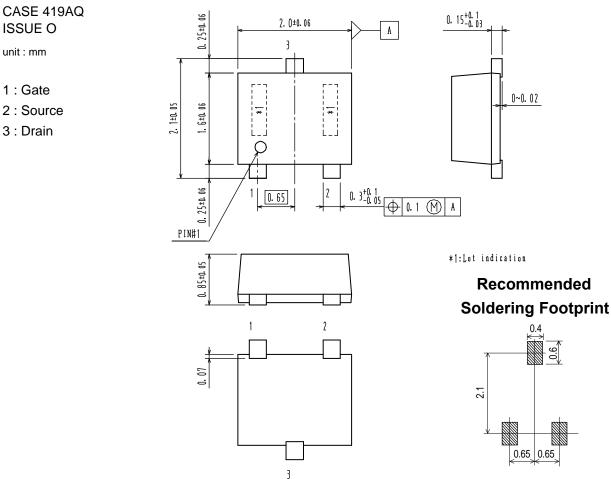
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Package Dimensions

MCH3484-TL-H / MCH3484-TL-W

MCPH3



ORDERING INFORMATION

Device	Package	Shipping	Note	
MCH3484-TL-H	MCPH3	3,000 pcs. / reel	Pb-Free	
MCH3484-TL-W	SC-70,SOT-323	0,000 pcs. / recr	and Halogen Free	

Note on usage : Since the MCH3484 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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